

RESEARCH HIGHLIGHT

Organic electronics: the nuclear option

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The conductivity of electronic materials is fundamentally determined by the interaction of its charge carriers with their environment. In devices based on conducting polymers, the dipole-mediated hyperfine interactions of polarons with the ubiquitous hydrogen nuclear spins are thought to be responsible for a range of phenomena including the extremely large magnetoresistive effects that are often seen.¹ Malissa *et al.*² have now demonstrated an elegant approach to investigating these effects in working devices by utilizing electron-nuclear double resonance and electron spin-echo envelope modulation, both detected by monitoring the change in the current through a poly[2-methoxy-5-(2-ethylhexyloxy)-1,4-phenylenevinylene] (MEH-PPV)-based organic light-emitting diode (see Figure 1).

Although conventional magnetic resonance spectroscopy is well suited to investigating electron-nuclear interactions in bulk materials, major difficulties exist when applying these techniques to thin-film devices under operating conditions (that is, biased and at room temperature). The number of spins in these devices is small, making detection difficult; conventional device architectures often distort the microwave pulses required for magnetic resonance and it can be challenging to distinguish between active spins, which influence device operation, and passive spins, which are present but have no practical influence.

The approach of the authors—the use of electrical readout in devices designed for the purpose—overcomes these issues by allowing a sensitive detection method, which implicitly measures only those spins that impact conductivity. It also allows the interactions to be investigated under device-operating conditions—biased and at room temperature. The effect is confirmed by deuterating one of the polymer side chains, with the expected change in observed resonance frequency.

Challenges remain. First, the short lifetime of the polarons ($T_1 \approx 40 \mu\text{s}$) limits their ability to probe coherent nuclear spin effects, an important step if these material are to be used for storing quantum information (as the authors suggest). Next, the

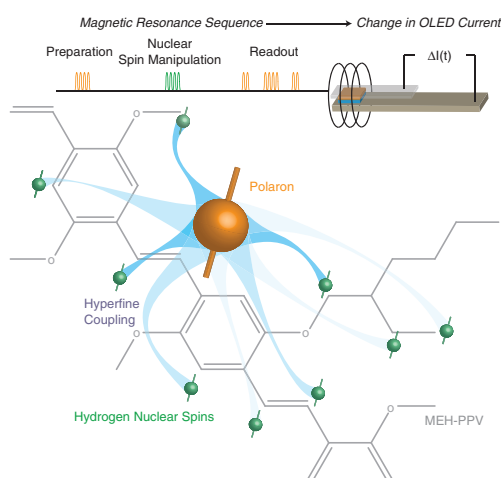


Figure 1 The current through an organic light emitting diode (OLED) is modified following nuclear magnetic resonance on the polymer's hydrogen atoms. A modified electron-nuclear double resonance sequence mediates this coupling. Owing to the long lifetime of nuclear spins, the authors propose that this may provide a way to store and readout information, although significant challenges remain, not least the short electron spin coherence and lifetimes. (Note that not all nuclei are shown here.)

approach is best suited to systems with coupling strengths that give resolved hyperfine resonances,³ but the material used here does not satisfy this condition due to the separation between the polaron (whose wavefunction resides mainly on the backbone) and the nuclei (which are mostly on the side chains). Nevertheless, the approach demonstrated here provides a useful technique for quantifying electron-nuclear interactions in a wide range of organic devices and materials and should find widespread application.

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